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N-Channel Power Trench[®] MOSFET 30 V, 16 A, 14.3 m Ω

Features

- Max r_{DS(on)} = 14.3 mΩ at V_{GS} = 10 V, I_D = 10.5 A
- Max r_{DS(on)} = 22.5 mΩ at V_{GS} = 4.5 V, I_D = 8.3 A
- High performance technology for extremely low r_{DS(on)}
- Termination is Lead-free and RoHS Compliant

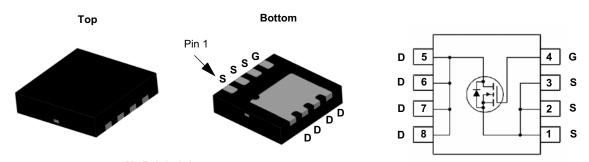


General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced Power Trench[®] process that has been especially tailored to minimize the on-state resistance. This device is well suited for Power Management and load switching applications common in Notebook Computers and Portable Battery Packs.

Application

- High side in DC DC Buck Converters
- Notebook battery power management
- Load switch in Notebook





MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units	
V _{DS}	Drain to Source Voltage			30	V	
V _{GS}	Gate to Source Voltage			±20	V	
	Drain Current -Continuous (Package limited)	T _C = 25 °C		16	A	
	-Continuous (Silicon limited)	T _C = 25 °C		34		
D	-Continuous	T _A = 25 °C	(Note 1a)	10.5		
	-Pulsed			40		
P _D	Power Dissipation	T _C = 25 °C		18	14/	
	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	W	
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C	

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	6.6	°C/W
$R_{ ext{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	53	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC8882	FDMC8882	MLP 3.3x3.3	13 "	12 mm	3000 units

May 2014

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units	
Off Chara	acteristics						
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	30			V	
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	I_D = 250 µA, referenced to 25 °C		25		mV/°C	
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 24 V, V _{GS} = 0 V T _J = 125 °C			1 250	μA	
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V			±100	nA	
On Chara	acteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \ \mu A$	1.2	1.9	2.5	V	
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = 250 µA, referenced to 25 °C		-5		mV/°C	
r _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 10.5 A		12.4	14.3	mΩ	
		V _{GS} = 4.5 V, I _D = 8.3 A		16.0	22.5		
		V _{GS} = 10 V, I _D = 10.5 A T _J = 125 °C		17.4			
9 _{FS}	Forward Transconductance	V _{DD} = 5 V, I _D = 10.5 A		33		S	
Dynamic	Characteristics						
C _{iss}	Input Capacitance			710	945	pF	
C _{oss}	Output Capacitance	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		140	185	pF	
C _{rss}	Reverse Transfer Capacitance			90	135	pF	
R _g	Gate Resistance			1.0		Ω	
Switching	g Characteristics						
t _{d(on)}	Turn-On Delay Time			7	14	ns	
t _r	Rise Time	V _{DD} = 15 V, I _D = 10.5 A,		3	10	ns	
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		17	30	ns	
t _f	Fall Time			2	10	ns	
0	Total Gate Charge	V _{GS} = 0 V to 10 V		14	20	nC	
Q _{g(TOT)}	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V V_{DD} = 15 V$		7	10	nC	
Q _{gs}	Total Gate Charge	I _D = 10.5 A		2.3		nC	
Q _{ad}	Gate to Drain "Miller" Charge			28		nC	

Drain-Source Diode Characteristics

Gate to Drain "Miller" Charge

V _{SD}	Source to Drain Diode Forward Voltage	V _{GS} = 0 V, I _S = 10.5 A (Note 2)	0.88	1.2	V
		V _{GS} = 0 V, I _S = 1.9 A (Note 2)	0.76	1.2	
t _{rr}	Reverse Recovery Time	I _E = 10.5 A, di/dt = 100 A/μs	16	28	ns
Q _{rr}	Reverse Recovery Charge	$-1_{\rm F} = 10.3$ A, di/dt = 100 A/µs	4.4	10	nC

NOTES:

 Q_{gd}

1. R_{0JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design.

a. 53 °C/W when mounted on a 1 in² pad of 2 oz copper



2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.

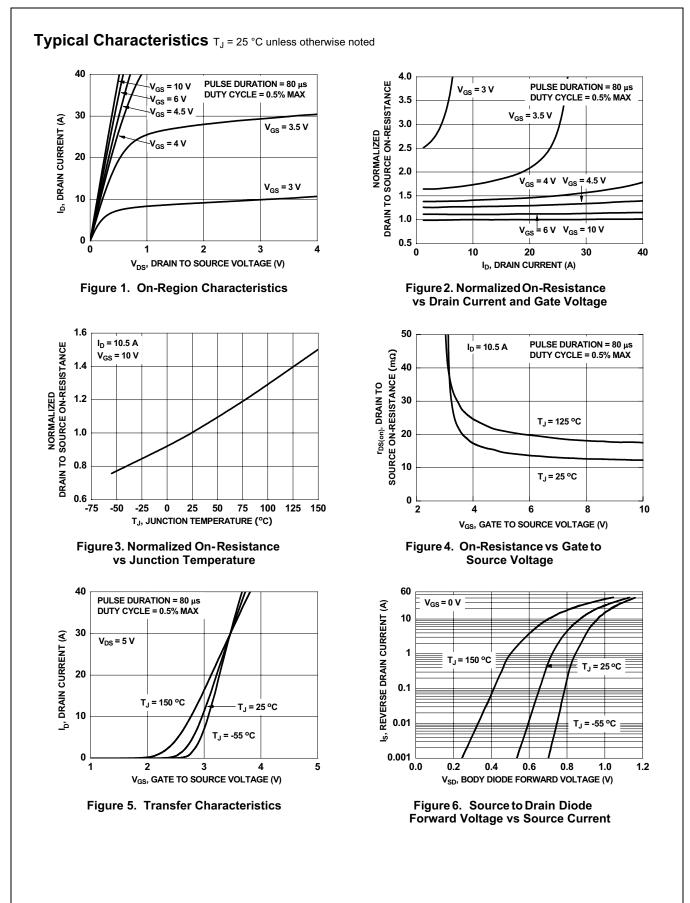
b.125 °C/W when mounted on a minimum pad of 2 oz copper

2.8



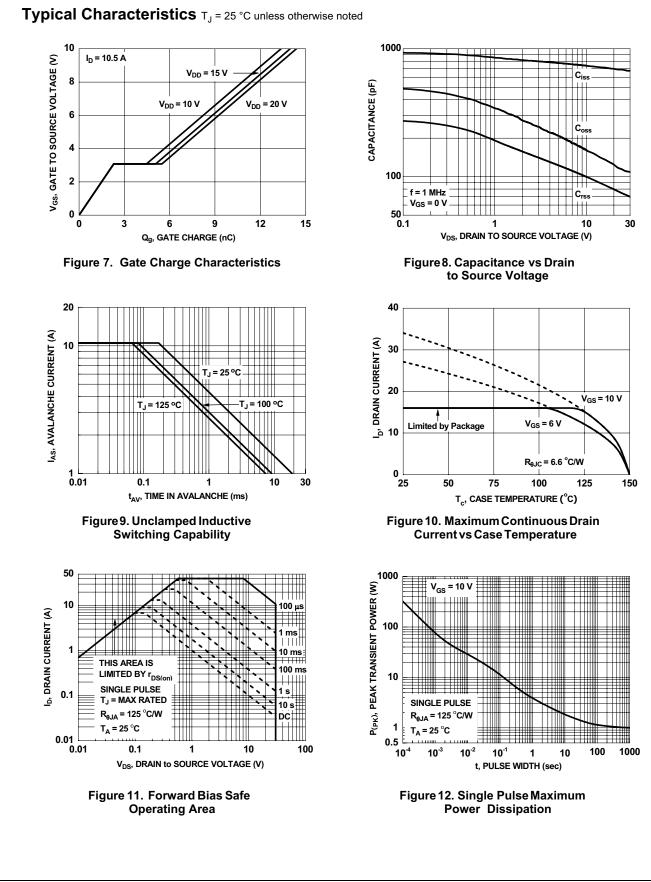
nC

FDMC8882 N-Channel Power Trench[®] MOSFET

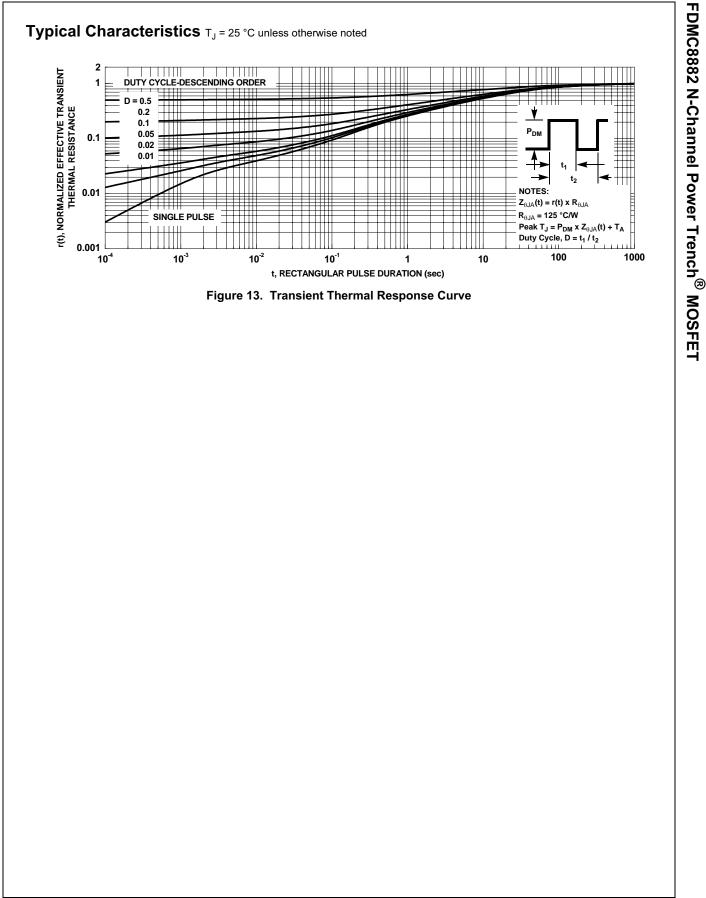


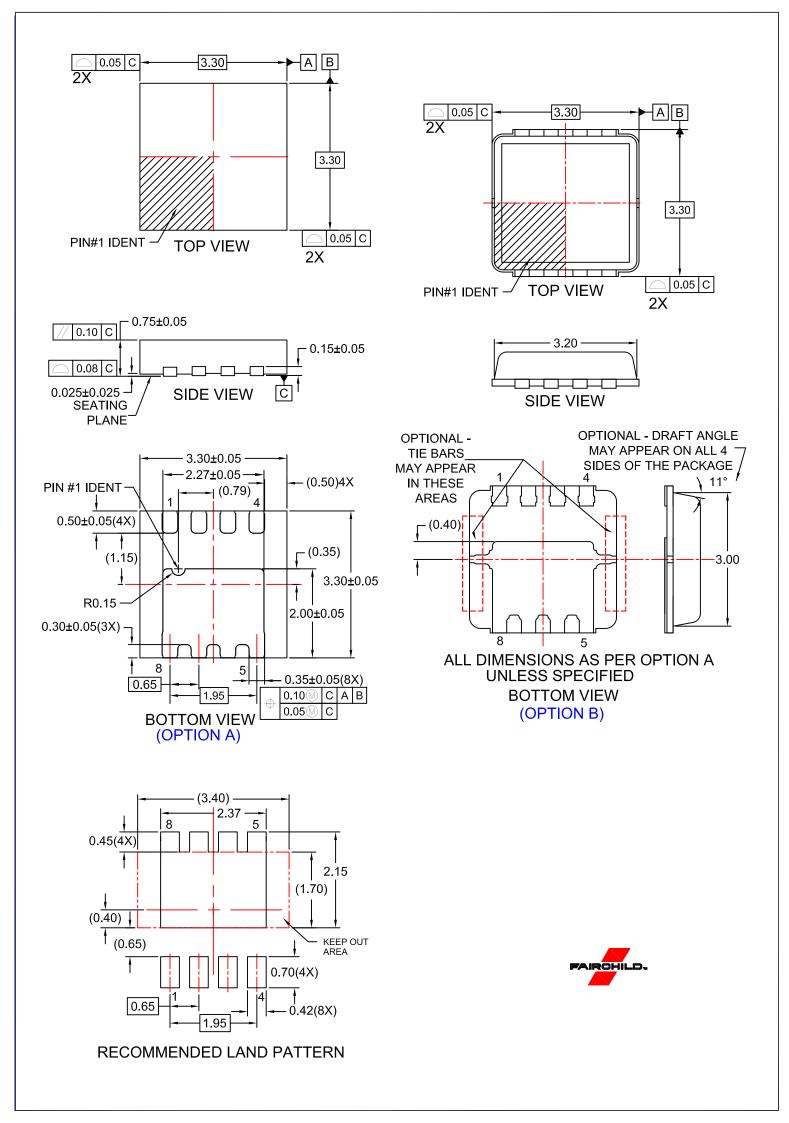
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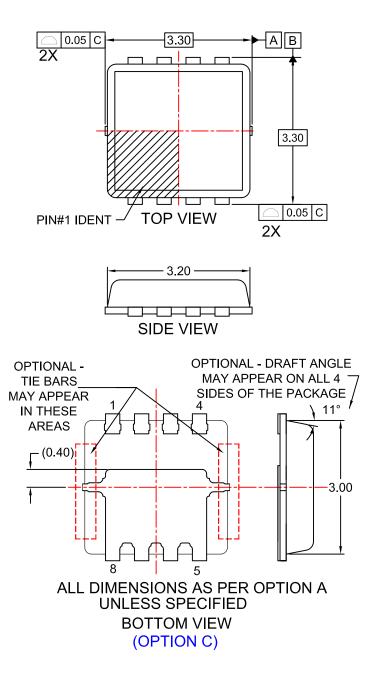




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NOTES:

- A. PACKAGE DOES NOT FULLY CONFORM TO JEDEC REGISTRATION MO-240.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
- D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN
- E. DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH. BURRS OR MOLD FLASH SHALL NOT EXCEED 0.10MM.
 F. DRAWING FILENAME: MKT-MLP08Wrev3.
- G. OPTION A SAWN MLP, OPTIONS B & C PUNCH MLP.



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